



GND

(TAB)

SOT-89 (Option 2)

 V_{OUT}



Description

The DIODES™ AP2202 is a 150mA ULDO regulator which provides very low noise, ultra-low dropout voltage (typically 165mV at 150mA), very low standby current (1µA maximum), and excellent power supply ripple rejection (PSRR 75dB at 100Hz). This device is used in battery-powered applications, such as handsets and PDAs; and in noise-sensitive applications, such as RF electronics.

The AP2202 also features logic-compatible enable/shutdown control inputs, a low power shutdown mode for extended battery life, overcurrent protection, over temperature protection, and reversed current protection.

The AP2202 has adjustable 2.5V, 2.6V, 2.8V, 3.0V, and 3.3V versions.

The AP2202 is available in the space-saving SOT-23-5 and SOT-89 packages.

(Top View) (Top View) 5 V_{OUT} 5 V_{OUT} GND [GND 4 BYP ΕN ΕN ADJ SOT-23-5 (Top View) (Top View) 1 3 1 2 3

Features

- Up to 150mA Output Current
- Low Standby Current
- Low Dropout Voltage: V_{DROP} = 165mV at 150mA
- High Output Accuracy: ±1%
- Good Ripple Rejection Ability: 75dB at 100Hz and I_{OUT} = 100μA
- Tight Load and Line Regulation
- Low Temperature Coefficient
- Overcurrent Protection
- Thermal Protection
- Reverse Current Protection
- Logic-Controlled Enable
- Lead-Free Packages: SOT-23-5, SOT-89
 - Totally Lead-Free; RoHS Compliant (Notes 1 & 2)
- Lead-Free Packages, Available in "Green" Molding Compound: SOT-23-5, SOT-89
 - Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
 - Halogen- and Antimony-Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Applications

Vout

GND

(TAB)

SOT-89 (Option 1)

 V_{IN}

- Cellular phones
- Cordless phones
- Digital still cameras

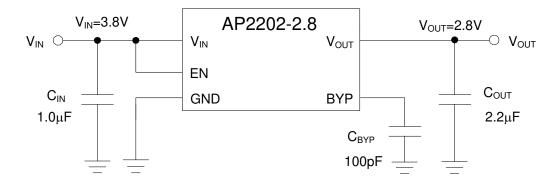
Pin Assignments

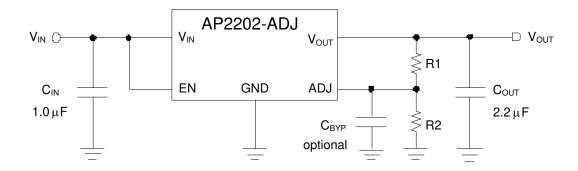
- Wireless communicators
- PDAs/palmtops
- PC mother boards
- Consumer electronics

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Typical Applications Circuit (Note 4)





V_{OUT}=1.25* (1+R2/R1)

Note:

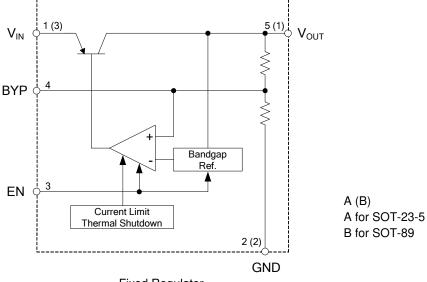
4. Dropout voltage is 165mV when T_A = +25°C. In order to obtain a normal output voltage, V_{OUT}+0.165V is the minimum input voltage which will result in a Low PSRR, imposing a bad influence on system. Therefore, the recommended input voltage is V_{OUT}+0.5V to 13.2V. For AP2202-2.8 version, its input voltage can be set from 3.3V (V_{OUT}+0.5V) to 13.2V. For that of ADJ version, any value from V_{OUT}+0.5V to 13.2V is available. R1 and R2 must be correctly selected when setting the output voltage. For example, if 3.0V output voltage is required, R1 and R2 can be set to 10kΩ and 14kΩ respectively. For ADJ version, we recommend 2.3V as minimum output voltage.

Pin Descriptions

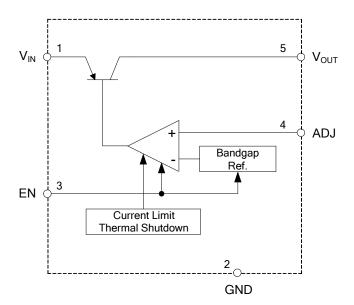
Pin Nı	umber	Pin Name	Function
SOT-23-5	SOT-89	Pin Name	Function
1	3	VIN	Input voltage
2	2	GND	Ground (TAB for SOT-89)
3	_	EN	Enable input: CMOS or TTL compatible input. Logic high = enable, logic low = shutdown
4	_	BYP/ADJ	Bypass capacitor for low noise operation/Adjust output
5	1	V _{OUT}	Regulated output voltage



Functional Block Diagram



Fixed Regulator



Adjustable Regulator



Absolute Maximum Ratings (Note 5)

Symbol	Parameter	Rating		Unit		
Vin	Supply Input Voltage	15		15		V
VEN	Enable Input Voltage	15	i	V		
PD	Power Dissipation	Internally Limited (T	hermal Protection)	W		
TLEAD	Lead Temperature (Soldering, 10sec)	+260		°C		
TJ	Junction Temperature	+15	60	°C		
Тѕтс	Storage Temperature	-65 to	+150	°C		
_	ESD (Machine Model)	20	0	V		
0	Theymal Desistance (No Heatsigh)	SOT-23-5	200	9CAM		
θμα	Thermal Resistance (No Heatsink)	SOT-89	165	°C/W		

Note:

Recommended Operating Conditions

Symbol	Parameter	Min	Мах	Unit
Vin	Supply Input Voltage	2.5	13.2	V
V _{EN}	Enable Input Voltage	0	13.2	V
TJ	Operating Junction Temperature	-40	+125	°C

^{5.} Stresses greater than those listed under *Absolute Maximum Ratings* can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to *Absolute Maximum Ratings* for extended periods can affect device reliability.



AP2202-ADJ Electrical Characteristics (@ $V_{IN} = V_{OUT} + 1V$, $I_{OUT} = 100\mu\text{A}$, $C_{IN} = 1.0\mu\text{F}$, $C_{OUT} = 2.2\mu\text{F}$, $V_{EN} \ge 2.0V$, $T_J = +25^{\circ}\text{C}$, **Bold** typeface applies over $-40^{\circ}\text{C} \le T_J \le +125^{\circ}\text{C}$ (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
			-1	_	1	
ΔVουτ/Vουτ	Output Voltage Accuracy	Variation from Specified Vout	-2	_	2	%
ΔVουτ/ΔΤ	Output Voltage Temperature Coefficient (Note 7)	_	_	120	_	μV/°C
.,		V V 4V 40 0V		0.004	0.012	0/ 0/
VRLINE	Line Regulation	$V_{IN} = V_{OUT} + 1V$ to 13.2V		_	0.05	%/V
.,	Load Degulation (Note 9)	1 0 do: A to 450 :: A	_	0.02	0.2	%
VRLOAD	Load Regulation (Note 8)	IOUT = 0.1mA to 150mA	_	_	0.5	%
		100.4	_	15	50	
		Ιουτ = 100μΑ		_	70	
			_	110	150	
.,	Dropout Voltage (Note 9)	IOUT = 50mA	_	_	230	
VDROP			_	140	250	mV
		IOUT = 100mA	_	_	300	
		I _{OUT} = 150mA		165	275	
				_	350	
	Otera dia a Command	V _{EN} ≤ 0.4V (Shutdown)		0.01	1	
ISTD	Standby Current	V _{EN} ≤ 0.18V (Shutdown)	_	_	5	μΑ
		V > 0.0V 0.4	_	95	130	
		$V_{EN} \ge 2.0V$, $I_{OUT} = 0\mu A$	_	_	150	
		V=-> 0.0V I= 100··A	_	98	140	
		V _{EN} ≥ 2.0V, I _{OUT} = 100μA	_	_	160	
Lava	Cround Din Current (Note 10)	\/> 0 0\/ 50m A	_	350	600	
IGND	Ground Pin Current (Note 10)	V _{EN} ≥ 2.0V, I _{OUT} = 50mA	_	_	800	μΑ
		\/> 0 0\/ 100m	_	600	1000	
		V _{EN} ≥ 2.0V, I _{OUT} = 100mA	_	_	1500	
		V > 0.0V 450mA	_	1300	1900	
		V _{EN} ≥ 2.0V, I _{OUT} = 150mA	_	_	2500	
PSRR	Ripple Rejection	Frequency = 100Hz, I _{OUT} = 100μA	_	75		dB
Ішміт	Current Limit	Vout = 0V	_	320	550	mA
e _{no}	Output Noise	I _{OUT} = 50mA, C _{OUT} = 2.2μF 100pF from BYP to GND		260	_	nV/\sqrt{Hz}



 $\textbf{AP2202-ADJ Electrical Characteristics} \text{ (continued) } (@V_{IN} = V_{OUT} + 1V, I_{OUT} = 100 \mu\text{A}, C_{IN} = 1.0 \mu\text{F}, C_{OUT} = 2.2 \mu\text{F}, C_{OUT}$ $V_{EN} \ge 2.0V$, $T_J = +25$ °C, **Bold** typeface applies over -40°C $\le T_J \le +125$ °C (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V	English languith and Languith and	Regulator Shutdown	_	_	0.4	V
VIL	Enable Input Logic-Low Voltage		_	_	0.18	V
ViH	Enable Input Logic-High Voltage	Regulator Enabled	2.0	_	_	V
	Enable Input Logic-Low Current	V _{IL} ≤ 0.4V	_	0.01	1	μΑ
lı∟		V _{IL} ≤ 0.18V	_	_	2	
	Frankla lament lamia Himb Commant	V _{IH} ≥ 2.0V	_	5	20	
Іін	Enable Input Logic-High Current	V _{IH} ≥ 2.0V	_	_	25	μΑ
0	Thermal Resistance	SOT-23-5	_	63.4	_	- °C/W
θυς	memai nesisiance	SOT-89	_	50	_	

- 6. Specifications in bold type are limited to -40°C ≤ T_J ≤ +125°C. Limits over temperature are guaranteed by design, but not tested in production.
- 7. Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.
- 7. Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.
 8. Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 150mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.
 9. Dropout voltage is defined as the input to output differential at which the output voltage drops 1% (T_J = +25°C) or 2% (-40°C ≤ T_J ≤ +125°C) below its nominal value measured at 1V differential.
- 10. Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.



AP2202-2.5 Electrical Characteristics (@ V_{IN} = 3.5V, I_{OUT} = 100μA, C_{IN} = 1.0μF, C_{OUT} = 2.2μF, V_{EN} ≥ 2.0V, T_{J} = +25°C, **Bold** typeface applies over -40°C ≤ T_{J} ≤ +125°C (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
			-1	_	1	- 1
ΔV out/ V out	Output Voltage Accuracy	Variation from Specified Vout	-2	_	2	%
ΔVουτ/ΔΤ	Output Voltage Temperature	_	_	120	_	μV/°C
$(\Delta V_{OUT}/V_{OUT})/\Delta T$	Coefficient (Note 7)	_	_	48	_	ppm/°C
	5		_	1	3	.,
VRLINE	Line Regulation	V _{IN} = 3.5V to 13.2V	_	_	13	mV
.,	1. 1.5. 1.1. (11.1.0)		_	1	5	.,
V_{RLOAD}	Load Regulation (Note 8)	I _{OUT} = 0.1mA to 150mA		_	13	mV
			_	15	50	
V _{DROP} Dropout Voltage (Note 9)		Ιουτ = 100μΑ	_	_	70	
	Dropout Voltage (Note 9)		_	110	150	
		I _{OUT} = 50mA		_	230	, ,
			_	140	250	mV
		I _{OUT} = 100mA		_	300	
	150.4	_	165	275		
		IOUT = 150mA	_	_	350	
	Observation Community	V _{EN} ≤ 0.4V (Shutdown)	_	0.01	1	
ISTD	Standby Current	V _{EN} ≤ 0.18V (Shutdown)	_	_	5	μΑ
		V > 0.0V I = 0. A	_	95	130	
		$V_{EN} \ge 2.0V$, $I_{OUT} = 0\mu A$	_	_	150	
		V > 0.0V L 400 A	_	98	140	
		V _{EN} ≥ 2.0V, I _{OUT} = 100μA	_	_	160	
	One and Die Ouwert (Nate 40)	V > 0.0V I = 50. A	_	350	600	
IGND	Ground Pin Current (Note 10)	V _{EN} ≥ 2.0V, I _{OUT} = 50mA	_	_	800	μΑ
		V > 0.0V L 400 A	_	600	1000	
		V _{EN} ≥ 2.0V, I _{OUT} = 100mA	_	_	1500	
		V > 0.0V 450A	_	1300	1900	
		V _{EN} ≥ 2.0V, I _{OUT} = 150mA	_	_	2500	00
PSRR	Ripple Rejection	Frequency = 100Hz, I _{OUT} = 100μA	_	75	_	dB
I _{LIMIT}	Current Limit	V _{OUT} = 0V	_	320	550	mA
e no	Output Noise	Iout = 50mA, Cout = 2.2μF 100pF from BYP to GND	_	260	_	nV/\sqrt{Hz}



AP2202-2.5 Electrical Characteristics (continued) (@ V_{IN} = 3.5V, I_{OUT} = 100μA, C_{IN} = 1.0μF, C_{OUT} = 2.2μF, V_{EN} ≥ 2.0V, $T_J = +25$ °C, **Bold** typeface applies over -40°C $\leq T_J \leq +125$ °C (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V	English languith and Languith and	Dogulates Chutelous	_	_	0.4	V
VIL	Enable Input Logic-Low Voltage	Regulator Shutdown	_	_	0.18	V
ViH	Enable Input Logic-High Voltage	Regulator Enabled	2.0	_	_	V
	Enable Input Logic-Low Current	V _{IL} ≤ 0.4V	_	0.01	1	μΑ
lı∟		V _{IL} ≤ 0.18V	_	_	2	
	Frankla lament lamia Himb Commant	V _{IH} ≥ 2.0V	_	5	20	
Іін	Enable Input Logic-High Current	V _{IH} ≥ 2.0V	_	_	25	μΑ
0	Thermal Resistance	SOT-23-5	_	63.4	_	- °C/W
θυς	memai nesisiance	SOT-89	_	50	_	

- 6. Specifications in bold type are limited to -40°C ≤ T_J ≤ +125°C. Limits over temperature are guaranteed by design, but not tested in production.
- 7. Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.
- ℓ. Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.
 8. Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 150mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.
 9. Dropout voltage is defined as the input to output differential at which the output voltage drops 1% (T_J = +25°C) or 2% (-40°C ≤ T_J ≤ +125°C) below its nominal value measured at 1V differential.
- 10. Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.



AP2202-2.6 Electrical Characteristics (@ $V_{IN} = 3.6V$, $I_{OUT} = 100\mu A$, $C_{IN} = 1.0\mu F$, $C_{OUT} = 2.2\mu F$, $V_{EN} \ge 2.0V$, $T_J = +25^{\circ}C$, **Bold** typeface applies over -40°C $\le T_J \le +125^{\circ}C$ (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
	Outrat Malla and Assurance	V	-1	_	1	٥/
ΔVουτ/Vουτ	Output Voltage Accuracy	Variation from Specified Vout	-2	_	2	%
ΔVουτ/ΔΤ	Output Voltage Temperature	_	_	120	_	μV/°C
$(\Delta V_{OUT}/V_{OUT})/\Delta T$	Coefficient (Note 7)	_	_	46	_	ppm/°C
V	Line Regulation	V 0 0V to 10 0V	_	1	3	m\/
VRLINE	Line Regulation	V _{IN} = 3.6V to 13.2V	_	_	13	mV
	Load Degulation (Note 9)	L 0.1 m A to 150 m A	_	1	6	mV
V _{RLOAD}	Load Regulation (Note 8)	I _{OUT} = 0.1mA to 150mA	_	_	14	mv
		100.4	_	15	50	
		Ιουτ = 100μΑ	_	_	70	
		I 50m A	_	110	150	
.,	Dropout Voltage (Note 9)	I _{OUT} = 50mA	_	_	230	
VDROP			_	140	250	mV
		I _{OUT} = 100mA	_	_	300	
		IOUT = 150mA	_	165	275	
				_	350	
	0	V _{EN} ≤ 0.4V (Shutdown)	_	0.01	1	
ISTD	Standby Current	V _{EN} ≤ 0.18V (Shutdown)	_	_	5	μΑ
		V > 0.0V I 0. A	_	95	130	
		$V_{EN} \ge 2.0V$, $I_{OUT} = 0\mu A$	_	_	150	
		V > 0.0V 400 A	_	98	140	
		V _{EN} ≥ 2.0V, I _{OUT} = 100μA	_	_	160	
	Crawad Bin Courset (Nate 10)	V >0.0V	_	350	600	
IGND	Ground Pin Current (Note 10)	V _{EN} ≥ 2.0V, I _{OUT} = 50mA	_	_	800	μΑ
		V > 0.0V 400 A	_	600	1000	
		V _{EN} ≥ 2.0V, I _{OUT} = 100mA	_	_	1500	
	V	_	1300	1900		
		V _{EN} ≥ 2.0V, I _{OUT} = 150mA	_	_	2500	
PSRR	Ripple Rejection	Frequency = 100Hz, I _{OUT} = 100μA	_	75	_	dB
I _{LIMIT}	Current Limit	V _{OUT} = 0V	_	320	550	mA
e no	Output Noise	IOUT = 50mA, COUT = 2.2μF 100pF from BYP to GND	_	260	_	nV/\sqrt{Hz}



AP2202-2.6 Electrical Characteristics (continued) (@ $V_{IN} = 3.6V$, $I_{OUT} = 100\mu A$, $C_{IN} = 1.0\mu F$, $C_{OUT} = 2.2\mu F$, $V_{EN} \ge 2.0V$, $T_J = +25^{\circ}C$, **Bold** typeface applies over $-40^{\circ}C \le T_J \le +125^{\circ}C$ (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
M _r .	Enable Input Logic-Low Voltage	Dogulator Chutdour	_	_	0.4	٧
VIL		Regulator Shutdown	_	_	0.18	V
V _{IH}	Enable Input Logic-High Voltage	Regulator Enabled	2.0	_	_	٧
1	Enable Input Logic-Low Current	V _{IL} ≤ 0.4V	_	0.01	1	
I _{IL}		V _{IL} ≤ 0.18V	_	_	2	μΑ
	Frankla kansak Lania Llink Commant	V _{IH} ≥ 2.0V	_	5	20	4
Іін	Enable Input Logic-High Current	V _{IH} ≥ 2.0V	_	_	25	μΑ
0	Thermal Resistance	SOT-23-5	_	63.4	_	9 C A M
θιс	Thermal nesistarice	SOT-89	_	50	_	- °C/W

- 6. Specifications in bold type are limited to $-40^{\circ}\text{C} \le T_{\text{J}} \le +125^{\circ}\text{C}$. Limits over temperature are guaranteed by design, but not tested in production.
- 7. Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.
- 8. Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 150mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.
- 9. Dropout voltage is defined as the input to output differential at which the output voltage drops 1% (T_J = +25°C) or 2% (-40°C ≤ T_J ≤ +125°C) below its nominal value measured at 1V differential.
- 10. Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.



AP2202-2.8 Electrical Characteristics (@ V_{IN} = 3.8V, I_{OUT} = 100μA, C_{IN} = 1.0μF, C_{OUT} = 2.2μF, V_{EN} ≥ 2.0V, T_{J} = +25°C, **Bold** typeface applies over -40°C ≤ T_{J} ≤ +125°C (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
			-1	_	1	
ΔV out/ V out	Output Voltage Accuracy	Variation from Specified Vout	-2	_	2	%
ΔVουτ/ΔΤ	Output Voltage Temperature	_	_	120	_	μV/°C
$(\Delta V_{OUT}/V_{OUT})/\Delta T$	Coefficient (Note 7)	_	_	42.8	_	ppm/°C
			_	1	4	
VRLINE	Line Regulation	V _{IN} = 3.8V to 13.2V	_	_	14	mV
.,	1. 1.5. 1.1. (11.1.0)		_	1	6	.,
V_{RLOAD}	Load Regulation (Note 8)	I _{OUT} = 0.1mA to 150mA		_	14	mV
			_	15	50	
		I _{OUT} = 100μA	_	_	70	
	Dropout Voltage (Note 9)		_	110	150	
		I _{OUT} = 50mA		_	230	.,
VDROP Dropout Voltage (Note 9)			_	140	250	- mV
		I _{OUT} = 100mA		_	300	
	150.4	_	165	275	1	
		IOUT = 150mA	_	_	350	
	Observation Community	V _{EN} ≤ 0.4V (Shutdown)	_	0.01	1	
ISTD	Standby Current	V _{EN} ≤ 0.18V (Shutdown)	_	_	5	μΑ
		V > 0.0V I 0. A	_	95	130	
		$V_{EN} \ge 2.0V$, $I_{OUT} = 0\mu A$	_	_	150	
		V - 200V I - 400 A	_	98	140	
		V _{EN} ≥ 2.0V, I _{OUT} = 100μA	_	_	160	
	One and Die Ouwert (Nate 40)	V - 0.0V I - 50 A	_	350	600	
IGND	Ground Pin Current (Note 10)	V _{EN} ≥ 2.0V, I _{OUT} = 50mA	_	_	800	μΑ
		V > 0.0V 400 mA	_	600	1000	
		V _{EN} ≥ 2.0V, I _{OUT} = 100mA	_	_	1500	
		V - 0.0V I - 450 A	_	1300	1900	
		V _{EN} ≥ 2.0V, I _{OUT} = 150mA	_	_	2500	
PSRR	Ripple Rejection	Frequency = 100Hz, I _{OUT} = 100μA	_	75	_	dB
I _{LIMIT}	Current Limit	V _{OUT} = 0V	_	320	550	mA
eno	Output Noise	IouT = 50mA, CouT = 2.2μF 100pF from BYP to GND	_	260	_	nV/\sqrt{Hz}



AP2202-2.8 Electrical Characteristics (continued) (@ V_{IN} = 3.8V, I_{OUT} = 100μA, C_{IN} = 1.0μF, C_{OUT} = 2.2μF, V_{EN} ≥ 2.0V, $T_J = +25$ °C, **Bold** typeface applies over -40°C $\leq T_J \leq +125$ °C (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V	English languith and Languith and	Dogulates Chutelous	_	_	0.4	V
VIL	Enable Input Logic-Low Voltage	Regulator Shutdown	_	_	0.18	V
ViH	Enable Input Logic-High Voltage	Regulator Enabled	2.0	_	_	V
	Enable Input Logic-Low Current	V _{IL} ≤ 0.4V	_	0.01	1	μΑ
lıL		V _{IL} ≤ 0.18V	_	_	2	
	Frankla lament lamia Himb Commant	V _{IH} ≥ 2.0V	_	5	20	
Іін	Enable Input Logic-High Current	V _{IH} ≥ 2.0V	_	_	25	μΑ
0	Thermal Resistance	SOT-23-5	_	63.4	_	- °C/W
θυς	memai nesisiance	SOT-89	_	50	_	

- 6. Specifications in bold type are limited to -40°C ≤ T_J ≤ +125°C. Limits over temperature are guaranteed by design, but not tested in production.
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 9. Dropout voltage is defined as the input to output differential at which the output voltage drops 1% (T_J = +25°C) or 2% (-40°C ≤ T_J ≤ +125°C) below its nominal value measured at 1V differential.
- 10. Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.



AP2202-3.0 Electrical Characteristics (@ $V_{IN} = 4V$, $I_{OUT} = 100\mu$ A, $C_{IN} = 1.0\mu$ F, $C_{OUT} = 2.2\mu$ F, $V_{EN} \ge 2.0V$, $T_J = +25$ °C, **Bold** typeface applies over -40°C ≤ $T_J \le +125$ °C (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
			-1	_	1	- 1
ΔV out/ V out	Output Voltage Accuracy	Variation from Specified Vout	-2	_	2	%
ΔVουτ/ΔΤ	Output Voltage Temperature	_	_	120	_	μV/°C
$(\Delta V_{OUT}/V_{OUT})/\Delta T$	Coefficient (Note 7)	_	_	40	_	ppm/°C
			_	1	4	
VRLINE	Line Regulation	V _{IN} = 4V to 13.2V	_	_	14	mV
			_	1	7	
V_{RLOAD}	Load Regulation (Note 8)	I _{OUT} = 0.1mA to 150mA	_	_	15	mV
			_	15	50	
		Ιουτ = 100μΑ	_	_	70	
	Dropout Voltage (Note 9)		_	110	150	
		I _{OUT} = 50mA	_	_	230	
VDROP			_	140	250	mV
		I _{OUT} = 100mA	_	_	300	
		IOUT = 150mA	_	165	275	
			_	_	350	
	Observation Community	V _{EN} ≤ 0.4V (Shutdown)	_	0.01	1	
ISTD	Standby Current	V _{EN} ≤ 0.18V (Shutdown)	_	_	5	μΑ
		V > 0.0V I = 0. A	_	95	130	
		$V_{EN} \ge 2.0V$, $I_{OUT} = 0\mu A$	_	_	150	
		V > 0.0V L 400 A	_	98	140	
		V _{EN} ≥ 2.0V, I _{OUT} = 100μA	_	_	160	
	One and Die Ouwent (Nate 40)	V > 0.0V I = 50. A	_	350	600	
IGND	Ground Pin Current (Note 10)	V _{EN} ≥ 2.0V, I _{OUT} = 50mA	_	_	800	μΑ
		V > 0.0V L 400 A	_	600	1000	
		V _{EN} ≥ 2.0V, I _{OUT} = 100mA	_	_	1500	
		V > 0.0V 450A	_	1300	1900	
		V _{EN} ≥ 2.0V, I _{OUT} = 150mA	_	_	2500	
PSRR	Ripple Rejection	Frequency = 100Hz, I _{OUT} = 100μA	_	75	_	dB
I _{LIMIT}	Current Limit	V _{OUT} = 0V	_	320	550	mA
e no	Output Noise	Iout = 50mA, Cout = 2.2μF 100pF from BYP to GND	_	260	_	nV/\sqrt{Hz}



AP2202-3.0 Electrical Characteristics (continued) (@ $V_{IN} = 4V$, $I_{OUT} = 100\mu A$, $C_{IN} = 1.0\mu F$, $C_{OUT} = 2.2\mu F$, $V_{EN} \ge 2.0V$, T_J = +25°C, **Bold** typeface applies over -40°C ≤ T_J ≤ +125°C (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
V	Enable Input Logic-Low Voltage	B 1 1 0 1 1	_	_	0.4	V	
VIL		Regulator Shutdown	_	_	0.18		
ViH	Enable Input Logic-High Voltage	Regulator Enabled	2.0	_	_	V	
I.	Enable Input Logic-Low Current	V _{IL} ≤ 0.4V	_	0.01	1		
lı∟		V _{IL} ≤ 0.18V	_	_	2	μΑ	
	Enable Input Logic-High Current	V _{IH} ≥ 2.0V	_	5	20		
Іін		V _{IH} ≥ 2.0V	_	_	25	μΑ	
θјс	Thermal Resistance	SOT-23-5	_	63.4	_	°C/W	
		SOT-89	_	50	_	C/VV	

- 6. Specifications in bold type are limited to -40°C ≤ T_J ≤ +125°C. Limits over temperature are guaranteed by design, but not tested in production.
- b. Specifications in bold type are limited to -40°C ≤ I_J ≤ +125°C. Limits over temperature are guaranteed by design, but not tested in production.
 7. Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.
 8. Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 150mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.
 9. Dropout voltage is defined as the input to output differential at which the output voltage drops 1% (T_J = +25°C) or 2% (-40°C ≤ T_J ≤ +125°C) below its nominal value measured at 1V differential.
 10. Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.
- current plus the ground pin current.



AP2202-3.3 Electrical Characteristics (@ $V_{IN} = 4.3V$, $I_{OUT} = 100\mu A$, $C_{IN} = 1.0\mu F$, $C_{OUT} = 2.2\mu F$, $V_{EN} \ge 2.0V$, $T_{J} = +25^{\circ}C$, **Bold** typeface applies over -40°C $\le T_{J} \le +125^{\circ}C$ (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
A)/	Output Voltage Accuracy	Variation from Cresified V	-1	_	1	%	
ΔVουτ/Vουτ	Output Voltage Accuracy	Variation from Specified Vout	-2	_	2		
ΔVουτ/ΔΤ	Output Voltage Temperature	_	_	120	_	μV/°C	
(ΔV _{OUT} /V _{OUT})/ΔΤ	Coefficient (Note 7)	_	_	36.3	_	ppm/°C	
	Line Regulation	V. 4 0V to 10 0V	_	1	5	mV	
VRLINE	Line negulation	V _{IN} = 4.3V to 13.2V	_	_	15		
V=	Load Regulation (Note 8)	love 0.1mA to 150mA	_	1	8	.,,	
V _{RLOAD}	Load negulation (Note 6)	I _{OUT} = 0.1mA to 150mA	_	_	17	mV	
		Love 100vA	_	15	50		
		Ιουτ = 100μΑ	_	_	70		
		L 50A	_	110	150		
	Dropout Voltage (Note 9)	I _{OUT} = 50mA	_	_	230	- mV	
VDROP		IOUT = 100mA	_	140	250		
			_	_	300		
		IOUT = 150mA	_	165	275		
			_	_	350		
1	Standby Current	V _{EN} ≤ 0.4V (Shutdown)	_	0.01	1		
ISTD	Standby Current	V _{EN} ≤ 0.18V (Shutdown)	_	_	5	μΑ	
	Ground Pin Current (Note 10)	V502 2 0V 1007 - 00A	_	95	130	μΑ	
		$V_{EN} \ge 2.0V$, $I_{OUT} = 0\mu A$	_	_	150		
		V > 0.0V L 400.4	_	98	140		
		V _{EN} ≥ 2.0V, louT = 100μA	_	_	160		
			_	350	600		
IGND		V _{EN} ≥ 2.0V, I _{OUT} = 50mA	_	_	800		
			_	600	1000		
		V _{EN} ≥ 2.0V, I _{OUT} = 100mA	_	_	1500		
		V	_	1300	1900		
		V _{EN} ≥ 2.0V, l _{OUT} = 150mA	_	_	2500		
PSRR	Ripple Rejection	Frequency = 100Hz, I _{OUT} = 100μA	_	75	_	dB	
I _{LIMIT}	Current Limit	V _{OUT} = 0V	_	320	550	mA	
e no	Output Noise	I _{OUT} = 50mA, C _{OUT} = 2.2μF 100pF from BYP to GND	_	260		nV/\sqrt{Hz}	



AP2202-3.3 Electrical Characteristics (continued) (@ $V_{IN} = 4.3V$, $I_{OUT} = 100\mu A$, $C_{IN} = 1.0\mu F$, $C_{OUT} = 2.2\mu F$, $V_{EN} \ge 2.0V$, $T_J = +25$ °C, **Bold** typeface applies over -40°C $\leq T_J \leq +125$ °C (Note 6), unless otherwise specified.)

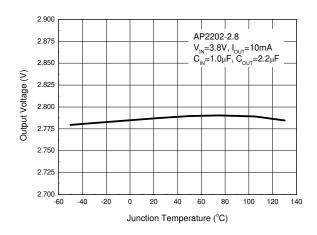
Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
	Enable Input Logic-Low Voltage	5 1	_	_	0.4	V	
VIL		Regulator Shutdown	_	_	0.18		
ViH	Enable Input Logic-High Voltage	Regulator Enabled	2.0	_	_	V	
lıL	Enable Input Logic-Low Current	V _{IL} ≤ 0.4V	_	0.01	1		
		V _{IL} ≤ 0.18V	_	_	2	μΑ	
1	Enable Input Logic-High Current	V _{IH} ≥ 2.0V	_	5	20	μΑ	
Іін		V _{IH} ≥ 2.0V	_	_	25		
θјс	Thermal Resistance	SOT-23-5	_	63.4	_	°C/W	
		SOT-89	_	50	_	C/VV	

- 6. Specifications in bold type are limited to -40°C ≤ T_J ≤ +125°C. Limits over temperature are guaranteed by design, but not tested in production.
- b. Specifications in bold type are limited to -40°C ≤ I_J ≤ +125°C. Limits over temperature are guaranteed by design, but not tested in production.
 7. Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.
 8. Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 150mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.
 9. Dropout voltage is defined as the input to output differential at which the output voltage drops 1% (T_J = +25°C) or 2% (-40°C ≤ T_J ≤ +125°C) below its nominal value measured at 1V differential.
 10. Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.
- current plus the ground pin current.

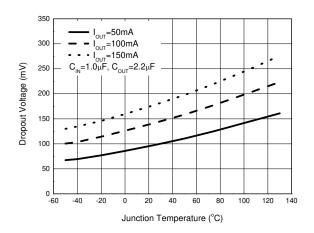


Performance Characteristics

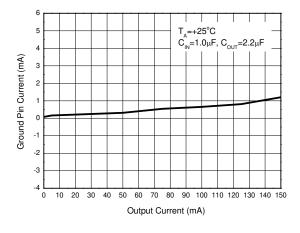
Output Voltage vs. Junction Temperature



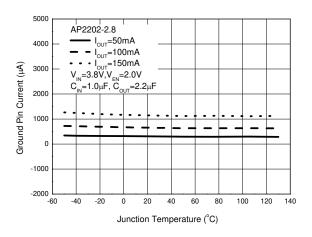
Dropout Voltage vs. Junction Temperature



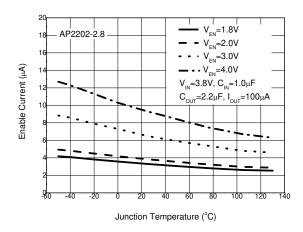
Ground Pin Current vs. Output Current



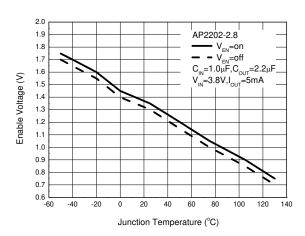
Ground Pin Current vs. Junction Temperature



Enable Current vs. Junction Temperature



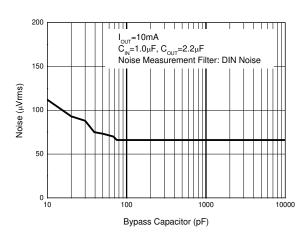
Enable Voltage vs. Junction Temperature



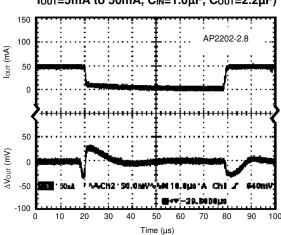


Performance Characteristics (continued)

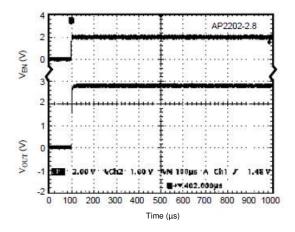
Noise vs. Bypass Capacitor



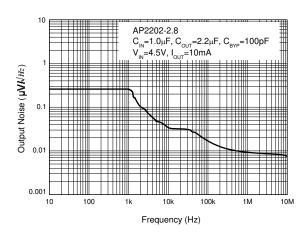
 $\label{lower} Load\ Transient \\ (Conditions: V_{IN}=3.8V,\ C_{BYP}=100pF,\ V_{EN}=2V, \\ I_{OUT}=5mA\ to\ 50mA,\ C_{IN}=1.0\mu F,\ C_{OUT}=2.2\mu F) \\ \end{array}$



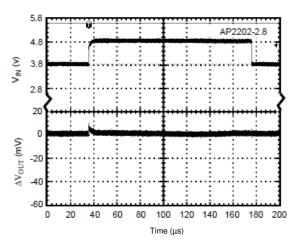
 $V_{EN}(on) \ vs. \ V_{OUT}$ (Conditions: V_{EN}=0V to 2V, V_{IN}=3.8V, I_{OUT}=30mA, C_{BYP}=open, C_{IN}=1.0 μ F, C_{OUT}=2.2 μ F)



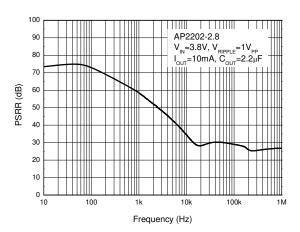
Output Noise vs. Frequency



 $\label{eq:line_line} Line Transient $$(Conditions: V_{IN}=3.8V \ to \ 4.8V, \ V_{EN}=2V, \ I_{OUT}=100\mu A$$$ $$C_{BYP}=100pF, \ C_{OUT}=10\mu F)$$



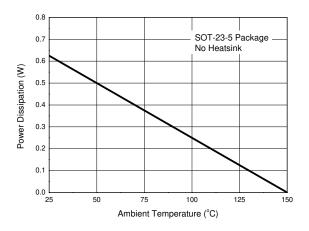
PSRR vs. Frequency



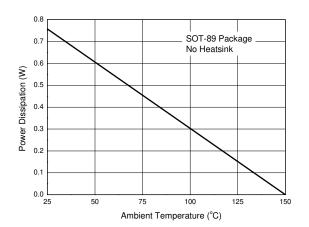


Performance Characteristics (continued)

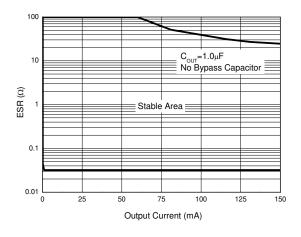
Power Dissipation vs. Ambient Temperature



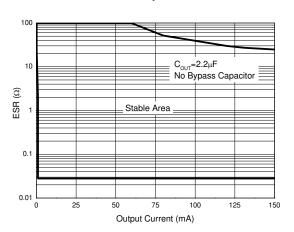
Power Dissipation vs. Ambient Temperature



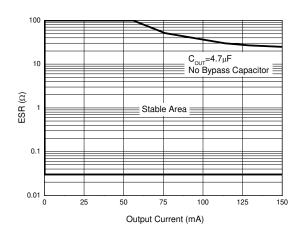
ESR vs. Output Current



ESR vs. Output Current



ESR vs. Output Current





Application Information

Input Capacitor

A 1µF minimum capacitor is recommended to be placed between V_{IN} and GND.

Output Capacitor

An output capacitor is required to prevent oscillation. A $1.0\mu F$ minimum is recommended when C_{BYP} is unused. A $2.2\mu F$ minimum is recommended when C_{BYP} is 100pF. The output capacitor may be increased to improve transient response.

Noise Bypass Capacitor

A bypass capacitor is connected to the internal voltage reference. A 100pF capacitor connected from BYP to GND makes this reference quiet, resulting in a significant reduction in output noise, but the ESR stable area will be narrowed.

The start-up speed of the AP2202 is inversely proportional to the value of the reference bypass capacitor. In some cases, if output noise is not a major concern and rapid turn-on is necessary, omit CBYP and leave BYP open.

Power Dissipation

Thermal shutdown may take place if the maximum power dissipation is exceeded in application. Under all possible operating conditions, the junction temperature must be within the range specified under absolute maximum ratings to avoid thermal shutdown.

To determine if the power dissipated in the regulator reaches the maximum power dissipation (see Figures Power Dissipation vs. Ambient Temperature (SOT-23-5 package and SOT-89 package)), use:

 $T_J = P_D^*\theta_{JA} + T_A$

 $P_D = (V_{IN}-V_{OUT})^*I_{OUT}+V_{IN}^*I_{GND}$

Where: $T_J \le T_{J(max)}$, $T_{J(max)}$ is absolute maximum ratings for the junction temperature; $V_{IN}^*I_{GND}$ can be ignored due to its small value.

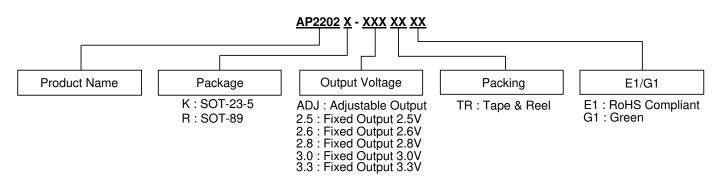
 $T_{J(max)}$ is +150°C, θ_{JA} is 200°C/W for SOT-23-5 package; and 165°C/W for SOT-89 package. No heatsink is required since the package alone will dissipate enough heat to satisfy these requirements, unless the calculated value for power dissipation exceeds the limit.

Example: For 2.8V version packaged in SOT-23-5, $I_{OUT} = 150$ mA, $T_A = +50$ °C, $V_{IN(Max)}$ is: (150°C-50°C)/(0.15A*200°C/W)+2.8V = 6.133V

Therefore, for good performance, please make sure that input voltage is less than 6.133V without heatsink when T_A = +50°C.



Ordering Information



Package	Temperature	Part Number		Marking ID		Packing	
	Range	RoHS Compliant (Note 11)	Green	RoHS Compliant	Green	Qty.	Carrier
	-40 to +125°C	AP2202K-ADJTRE1	AP2202K-ADJTRG1	E2C	G2C	3k	Tape & Reel
		AP2202K-2.5TRE1	AP2202K-2.5TRG1	E2D	G2D	3k	Tape & Reel
SOT-23-5		AP2202K-2.6TRE1	AP2202K-2.6TRG1 (Note 11)	E2E	G2E	3k	Tape & Reel
		AP2202K-2.8TRE1	AP2202K-2.8TRG1 (Note 11)	E2G	G2G	3k	Tape & Reel
		AP2202K-3.0TRE1	AP2202K-3.0TRG1	E2I	G2I	3k	Tape & Reel
		AP2202K-3.3TRE1	AP2202K-3.3TRG1	E2L	G2L	3k	Tape & Reel
SOT-89	-40 to +125°C	AP2202R-3.3TRE1	AP2202R-3.3TRG1	E22B	G22B	3k	Tape & Reel

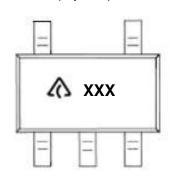
Note:

11. Not recommended for new design.

Marking Information

(1) SOT-23-5

(Top View)

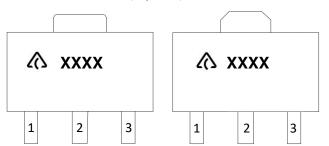


2(3 : Log

XXX: Marking ID (See Ordering Information)

(2) SOT-89

(Top View)



(() : Logo

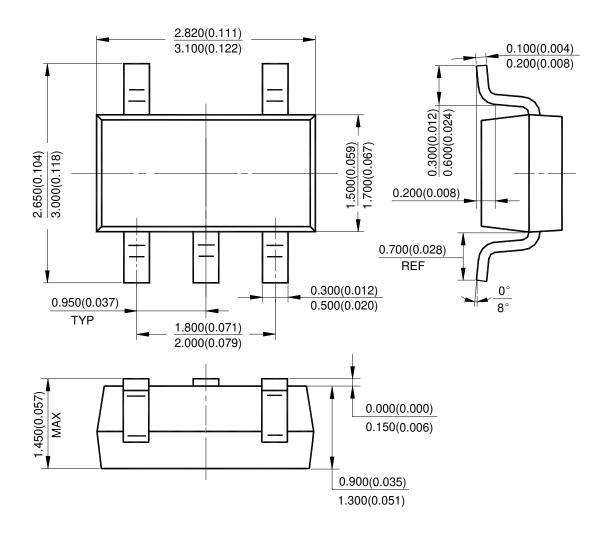
XXXX: Marking ID (See Ordering Information)



Package Outline Dimensions (All dimensions in mm(inch).)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT-23-5

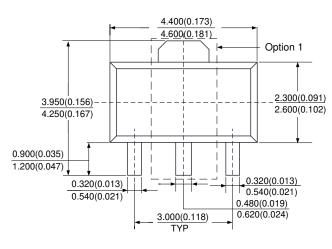


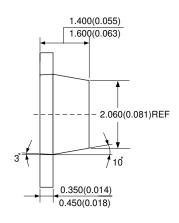


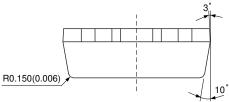
Package Outline Dimensions (continued) (All dimensions in mm(inch).)

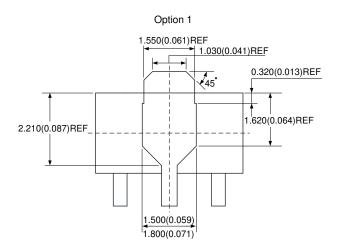
Please see http://www.diodes.com/package-outlines.html for the latest version.

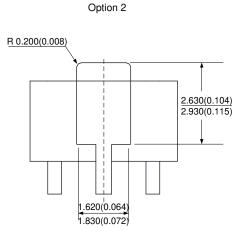
(2) Package Type: SOT-89









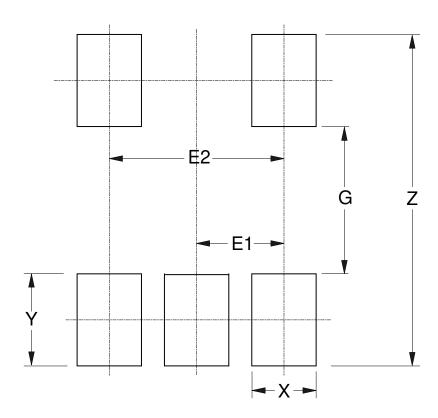




Suggested Pad Layout

 $Please\ see\ http://www.diodes.com/package-outlines.html\ for\ the\ latest\ version.$

(1) Package Type: SOT-23-5



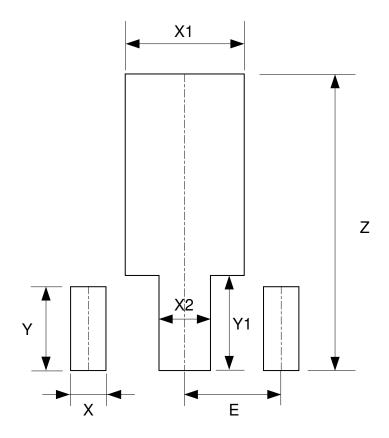
Dimensions	Z	G	X	Y	E1	E2
	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)
Value	3.600/0.142	1.600/0.063	0.700/0.028	1.000/0.039	0.950/0.037	1.900/0.075



Suggested Pad Layout (continued)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(2) Package Type: SOT-89



Dimensions	Z	X	X1	X2	Y	Y1	E
	(mm)/(inch)						
Value	4.600/0.181	0.550/0.022	1.850/0.073	0.800/0.031	1.300/0.051	1.475/0.058	1.500/0.059

Mechanical Data

- Moisture Sensitivity: Level 3 Per J-STD-020
- Terminals: SOT-23-5/SOT-89 Finish—Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight:
 - SOT-23-5: 0.015 grams (Approximate)
 - SOT-89: 0.055 grams (Approximate)



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